

Development of a Laser Test Stand for SiPMs for CMS HGCAL

Timo Christian
CALICE Collaboration Meeting
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HELMHOLTZ



UNIVERSITÄT
HEIDELBERG
ZUKUNFT
SEIT 1386



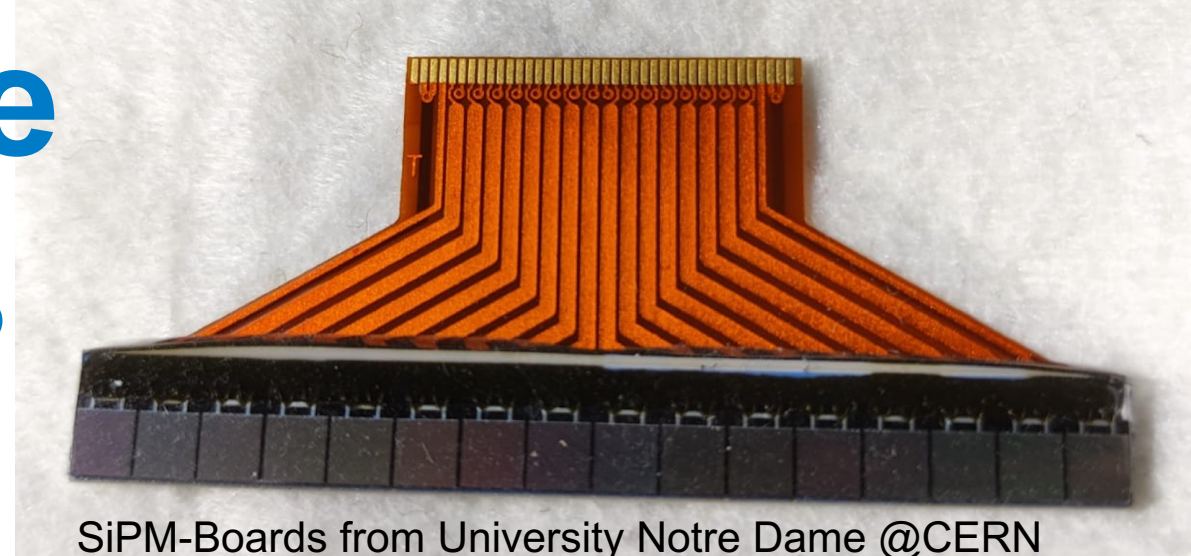
Outline

- **Motivation**
 - Quality Assurance
 - SiPM-Saturation
- **Laser Test Stand**
 - Schematic
 - Realisation
 - Measurement Box
- **Summary and Outlook**

Motivation

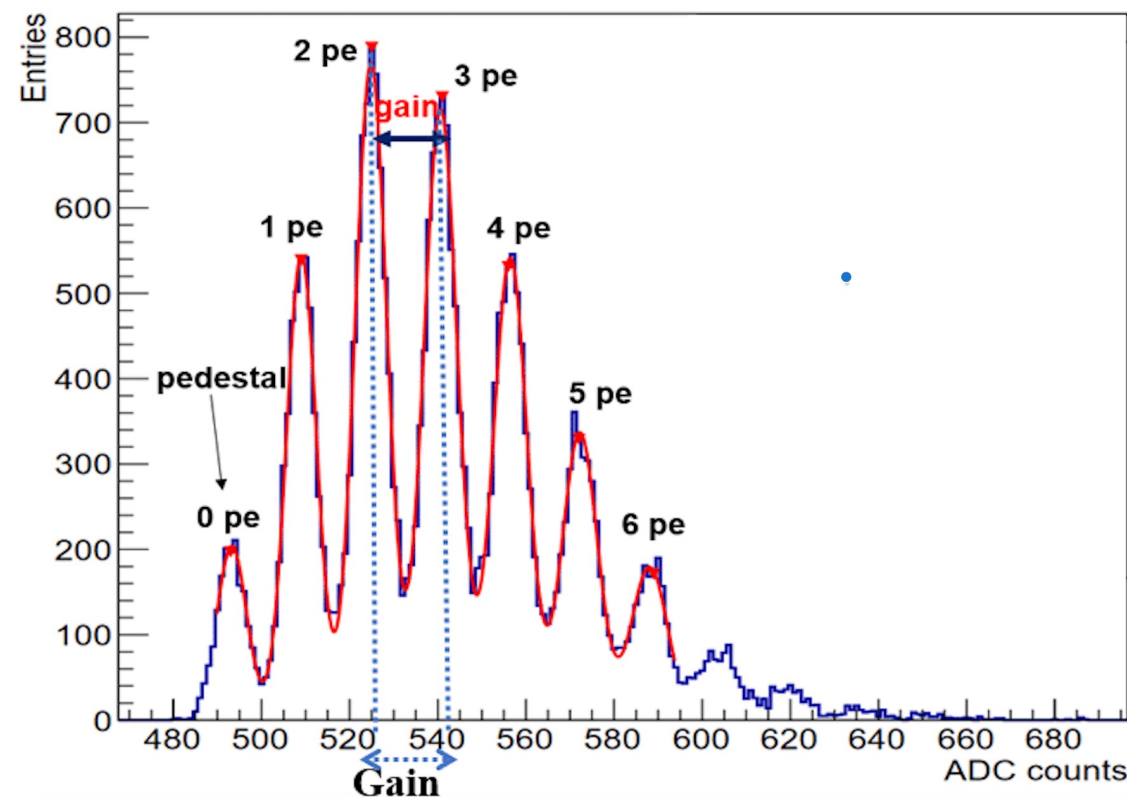
- 1) **Quality Assurance for HGCAL SiPMs**
- 2) **Saturation Analysis at high illumination for HGCAL SiPMs**

Quality Assurance for HGICAL SiPMs



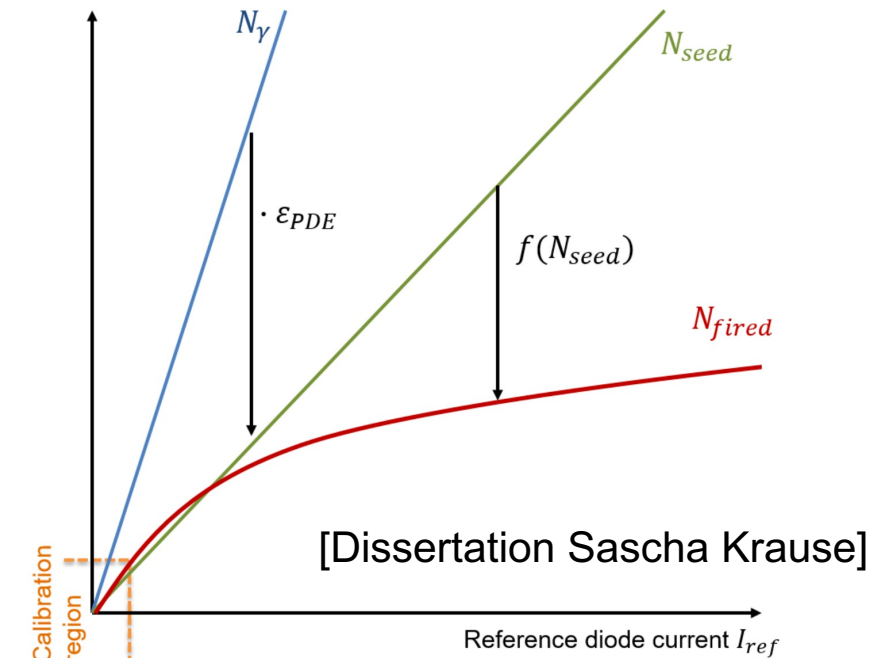
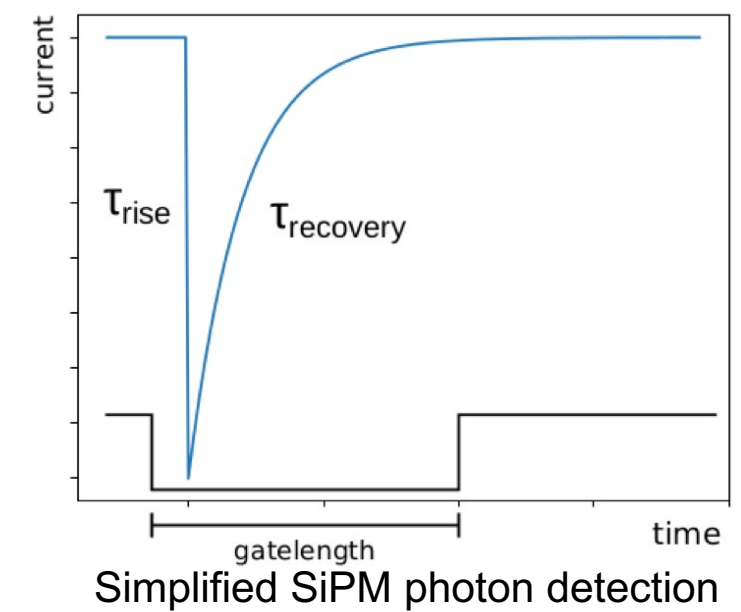
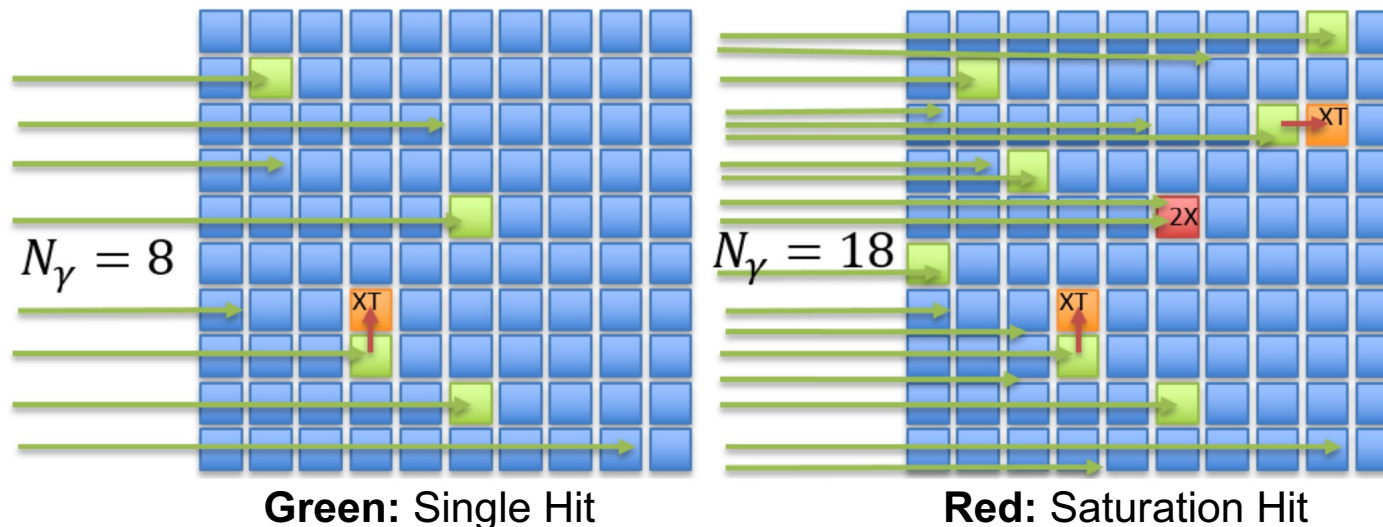
SiPM-Boards from University Notre Dame @CERN

- **Uniformity** in produced charges from Hamamatsu
- Characteristic **SiPM parameters**:
 - Gain
 - Overvoltage
 - Dark Count Rate
 - **Saturation?**
- Reuse CERN SiPM-Boards holding 16 SiPMs:
 - Previously used for current-based QA of HGICAL und BTL SiPM
- **Quantities:**
 - 1.0 - 1.5 % of HGICAL SiPMs
 - 2000-3000 SiPMs (80 - 100 SiPM-Boards)
 - Measure 2 Boards simultaneously



SiPM-Saturation

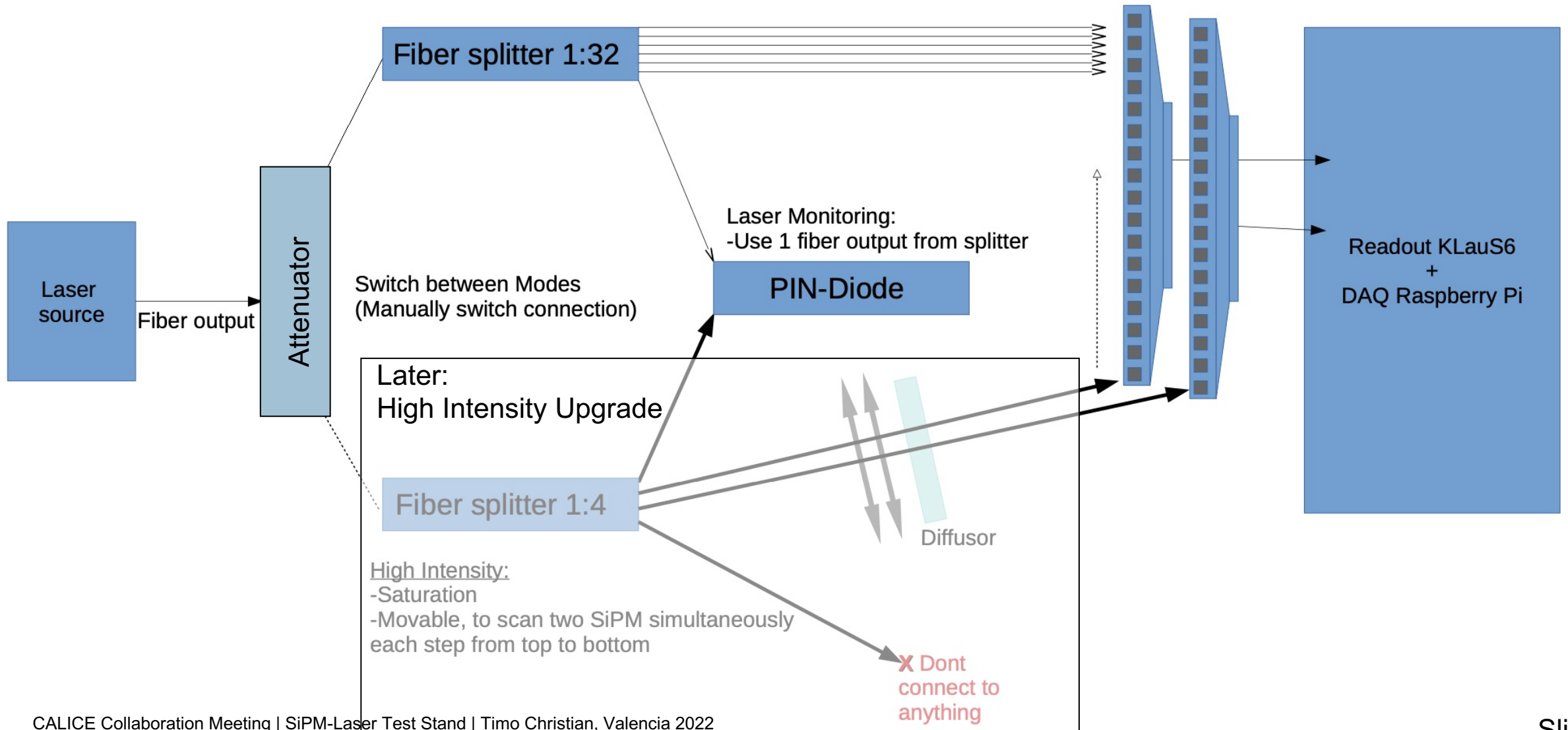
- Saturation effects due to pixel recovery
- High illumination non-linear SiPM response
- Simplest model:
$$f_{Saturation} = N_{Pixel} \left(1 - \exp \left(- \frac{\epsilon_{PDE} \cdot N_{\gamma}}{N_{Pixel}} \right) \right)$$
- Require 1 million photons for a SiPM with 40000 pixel
- Uniformity in charges (device to device)



Laser Test Stand-Schematic

Low Intensity:

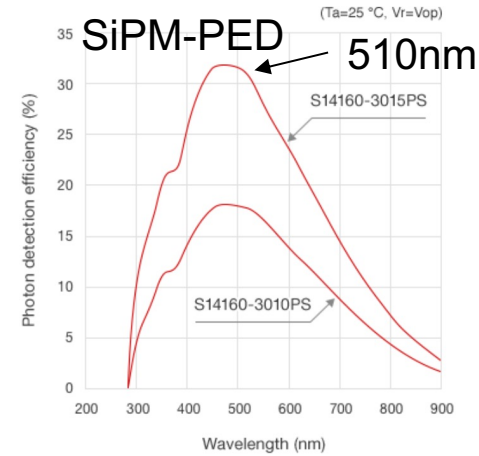
- SPS + Calibration
- All SiPM simult.



Realisation

Laser source: Pulsed Picosecond Laser

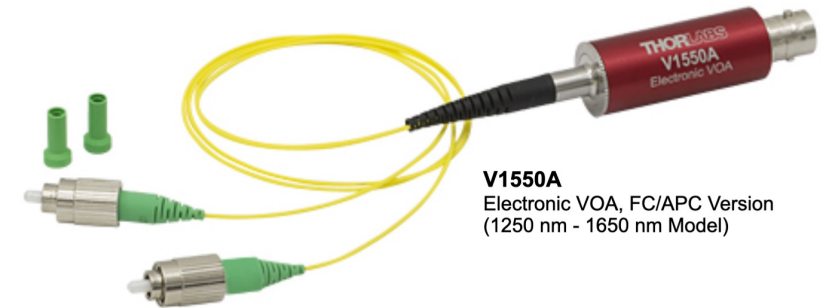
- 510 nm photon wavelength
- 0.2 mW average power at 40 MHz
- Corresponds to 12 million photons per pulse



Electronic variable optical attenuator + fixed attenuators:

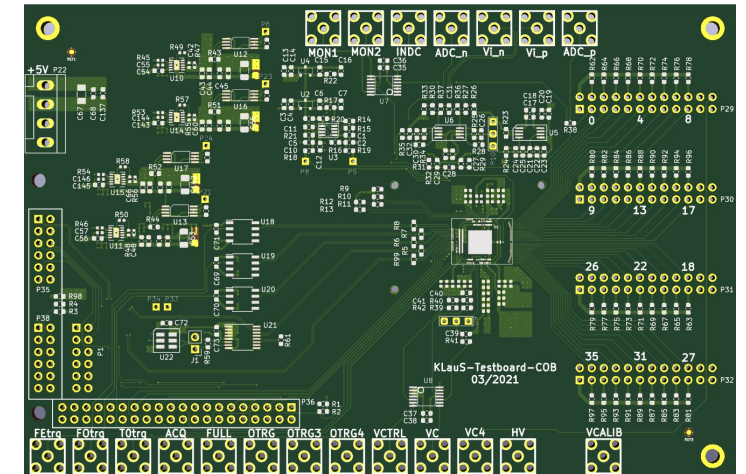
reduce 12 million photons to Single Photons Spectra (SPS) (~10 Photons)

- Three fixed attenuators á 15 dB
 - One variable attenuator 0-30 dB
- Up to 75 dB controlled attenuation
(+fix attenuation from splitters and connectors)



KLauS6-Board (Kanaele fuer Ladungsauslese von SiPM) + Raspberry Pi:

- 36-channel ASIC
- High precision charge measurement with integrated ADC/TDC
- Charge: Dynamic range up to 450pC (4 gain configurations: High-Gain down to Ultra-Low-Gain)
- Timing: Dynamic range 3.2ms with 200ps bin sized timestamps utilizing a 40MHz reference clock
- Low power consumption: 3.6mW/chn full operation



Measurement Box

Interlock Darkbox:

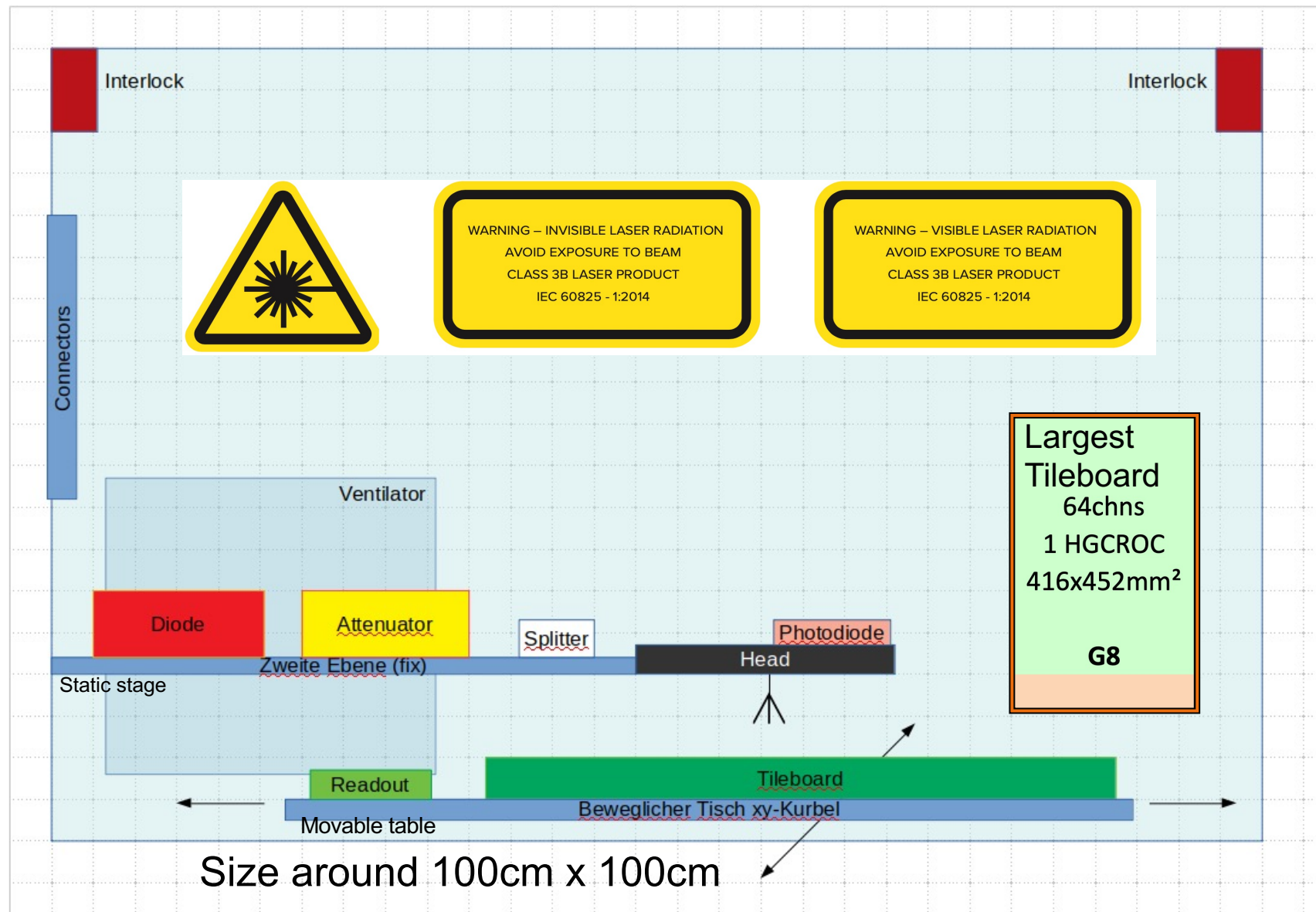
- 3B-Class Laser demands safety measures

Therefore:

- Create **large** scale interlock box to **be able to advance** from my **KLauS-Setup** to **HGCAL-Tileboard** setup in the further future
- **Saturation** evaluation with possible **HGCROC** non-linearities
- Consider complex geometries
- One fiber output, move tileboard in xy-plane to reach every channel
- **Reminder:** KLauS+SiPM-Board much smaller and easy geometry

Received recommendation:

- Completely separate darkbox and laser diode to guarantee clean measurements



Summary and Outlook

Motivation:

- HGCal SiPM quality control in large quantities
- Understand SiPM behavior for large signals

Status:

- Design process of a secure darkbox
- Assemble fiber system
- Testing and understanding KLauS-Sensorboard

Outlook:

- First tests of multiple SiPMs
- Installation of the laser + control
- First full SiPM-Board evaluation with laser

Kontakt

Deutsches Elektronen-
Synchrotron DESY

Timo Christian
FTX, DTA

www.desy.de

Timo.christian@desy.de

Backup

SiPM-Saturation II

PROTOTYPE No. S16713-01(ES1), -02(ES1), -03(ES1)

Three different SiPM sizes:

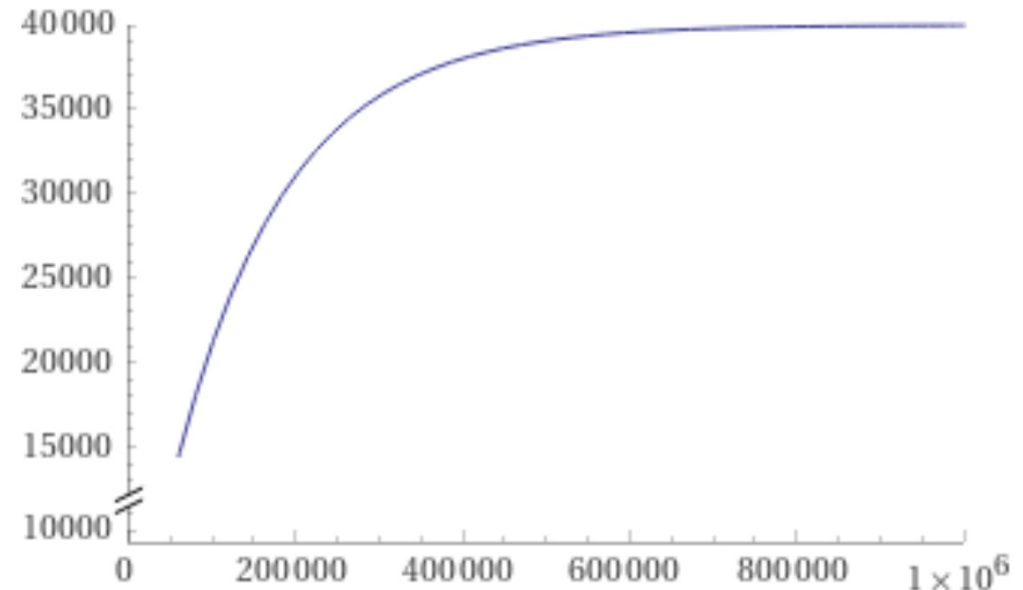
9000 pixel on 1.4x1.4 mm²

17000 pixel on 2.0x2.0 mm²

40000 pixel on 3.0x3.0 mm²

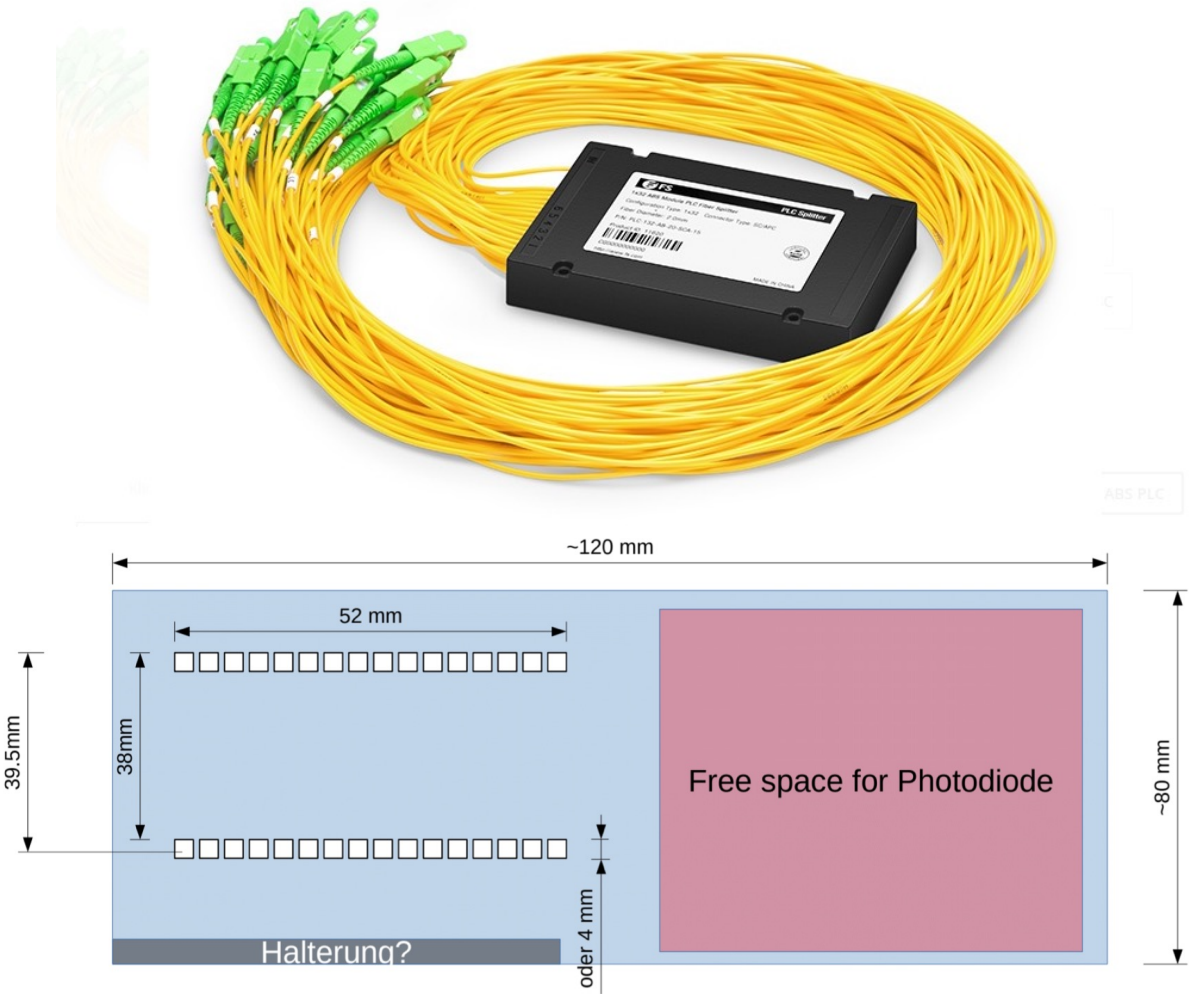
Simplest Exponential Model:

$$f_{\text{Saturation}} = N_{\text{Pixel}} \left(1 - \exp \left(- \frac{\epsilon_{\text{PDE}} \cdot N_{\gamma}}{N_{\text{Pixel}}} \right) \right)$$



Fiber Head for Quality Assurance

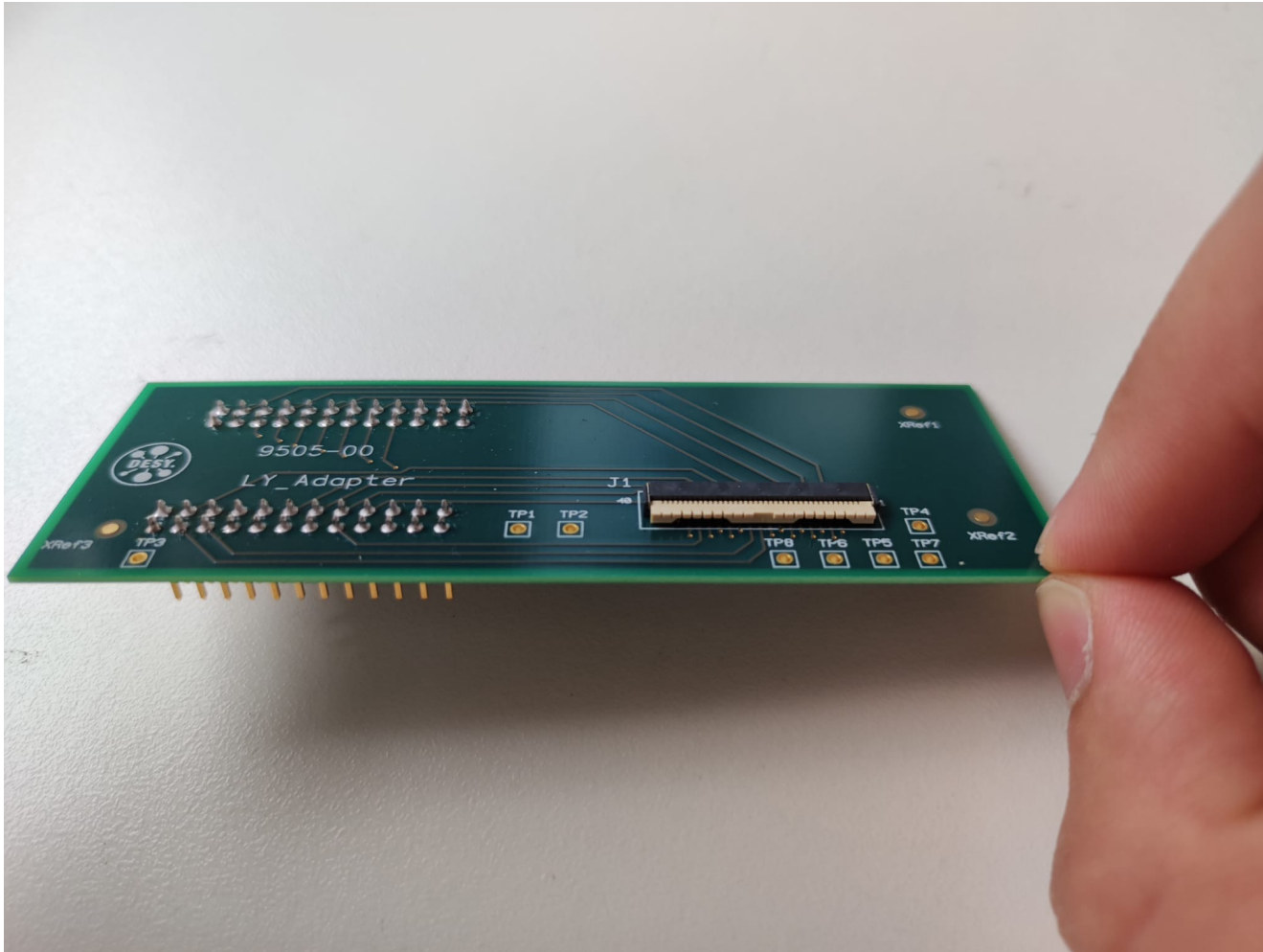
- Splitter 1x32, off spectrum (1200-1600nm)
- Plastic head holding fibers
- No movement required
- Laser monitoring with a Si detector element



Item #	Wavelength	Detector	Bandwidth	Max Peak Power	Rise Time	Fall Time
DET02AFC	400 - 1100 nm	Si	1 GHz	18 mW	1 ns (Max)	1 ns (Max)
DET025AFC	400 - 1100 nm	Si	2 GHz	18 mW	150 ps (Typ.)	150 ps (Typ.)

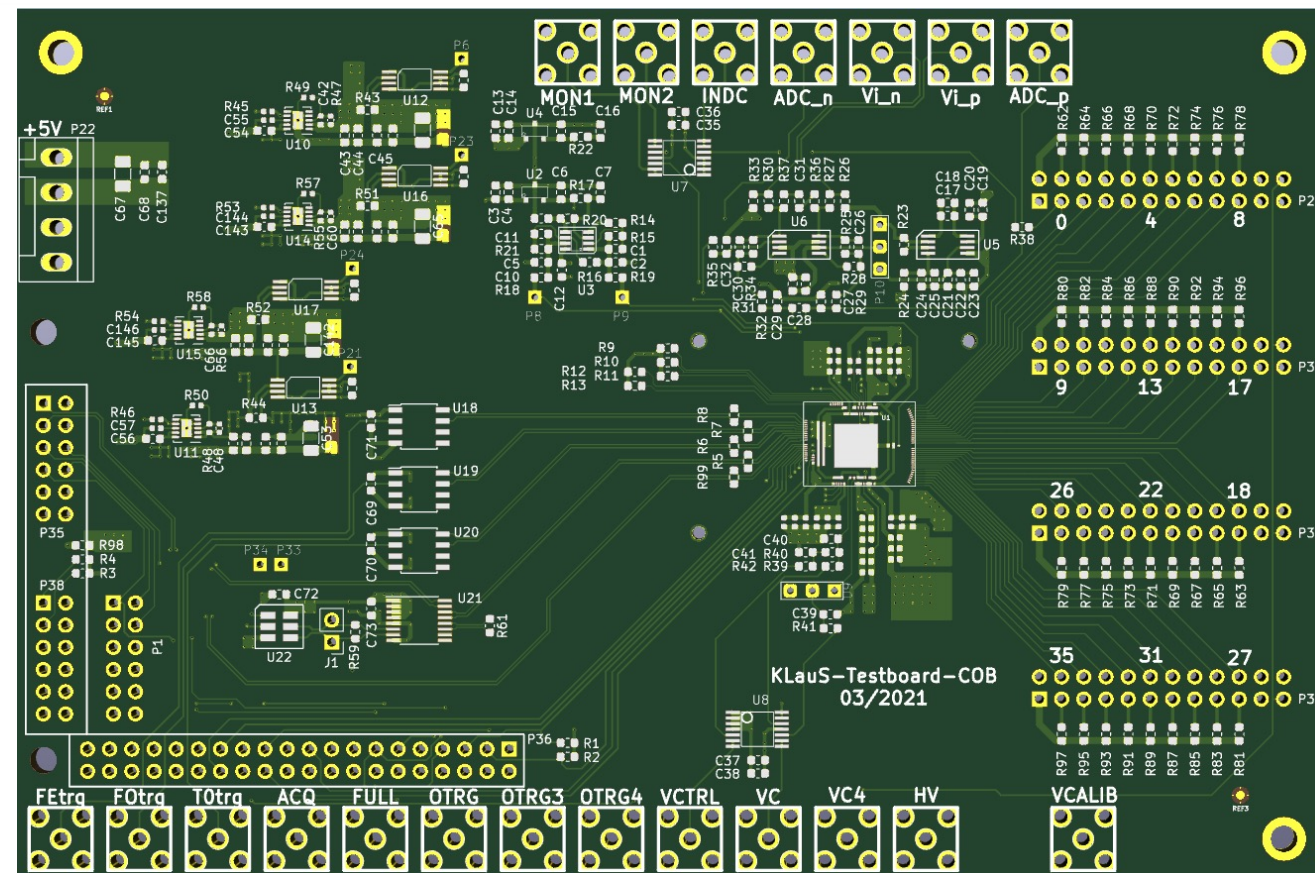
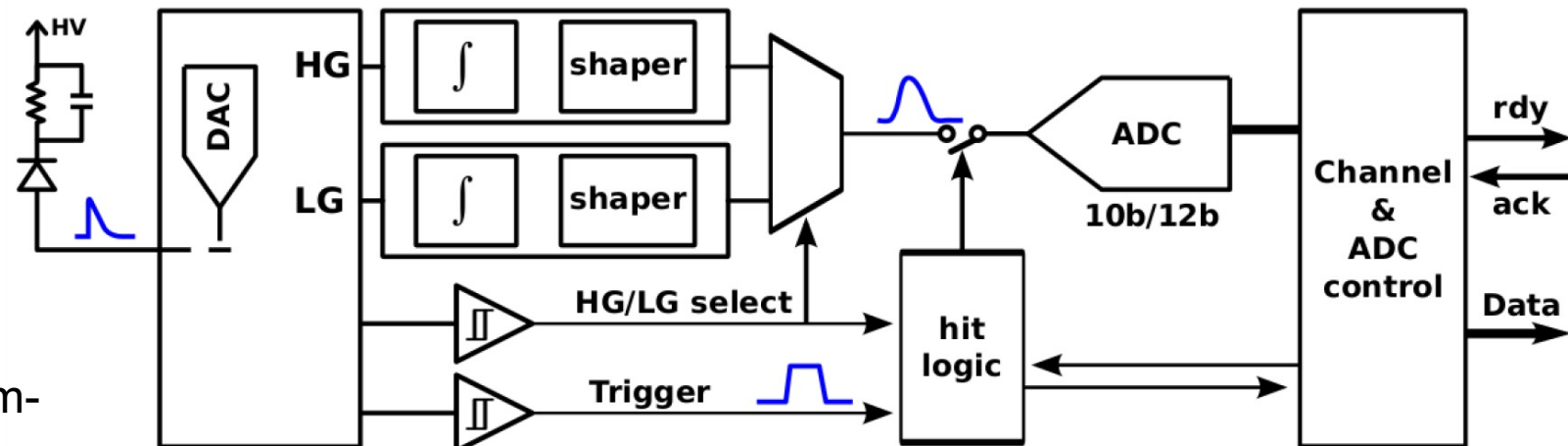


Adapter and Fiber Head



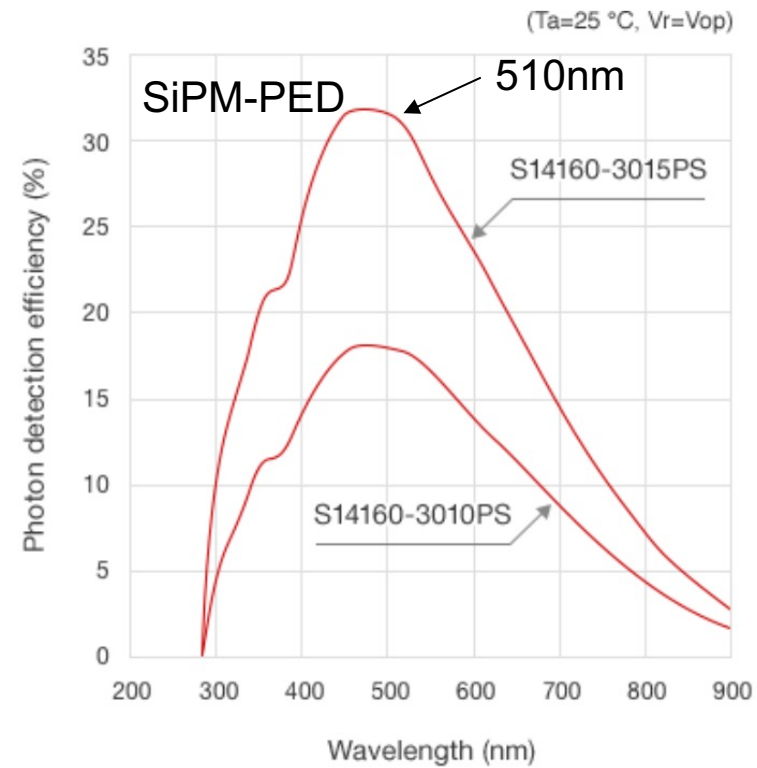
Kanäle für die Ladungsauslese von Silizium-Photomultipliern:

- 36-channel ASIC
- Auto/External triggered
- High precision charge measurement with integrated ADC/TDC
- Charge: Dynamic range up to 450pC (4 gain configurations: High-Gain down to Ultra-Low-Gain)
- Timing: Dynamic range 3.2ms with 200ps bin sized timestamps utilizing a 40MHz reference clock
- Low power consumption: 3.6mW/chn full operation

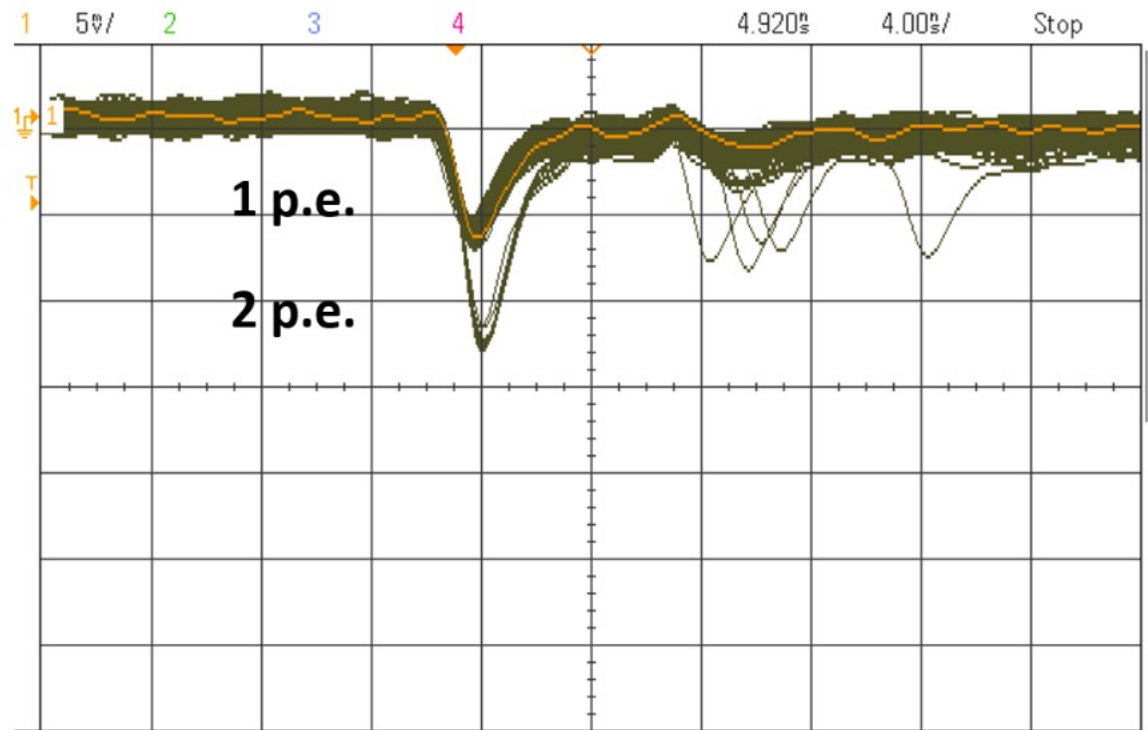
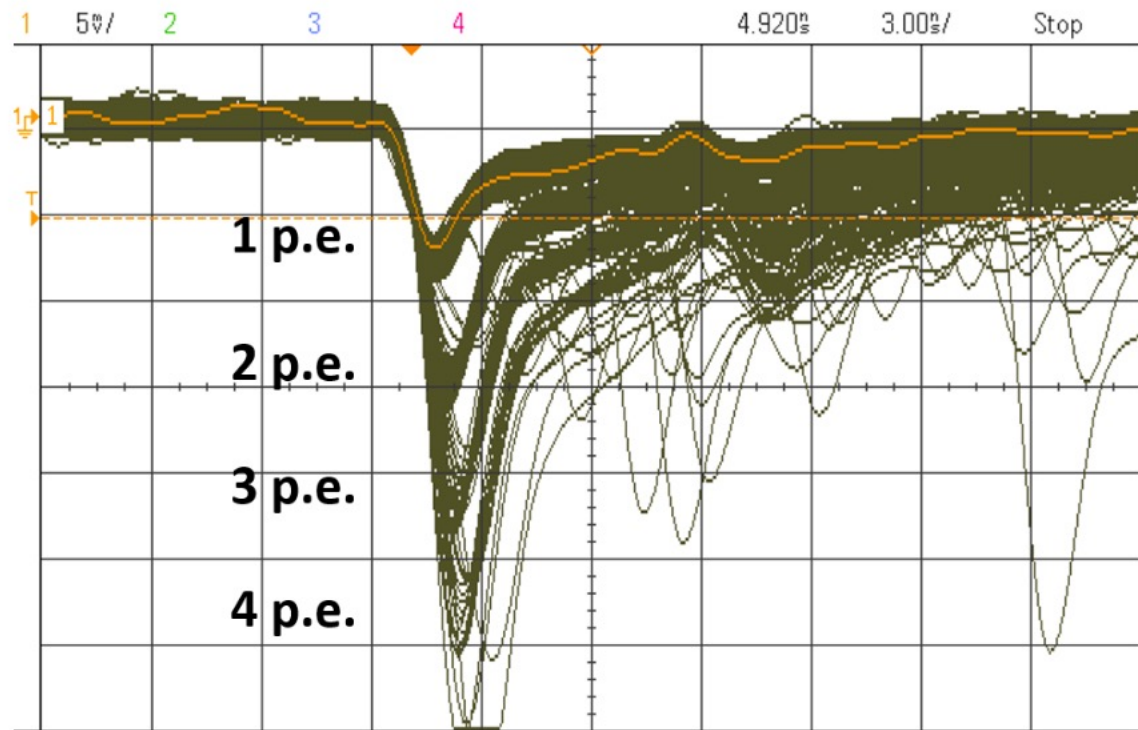


Laser

Model	Output	Wavelength	Spectral width	Pulse width	Peak power	Avg. power ¹⁾	Max. repetition rate
PIL051-FC	FC/APC	510 ± 15 nm	< 10 nm	< 110 ps	> 40 mW	> 0.2 mW	40 MHz



Crosstalk

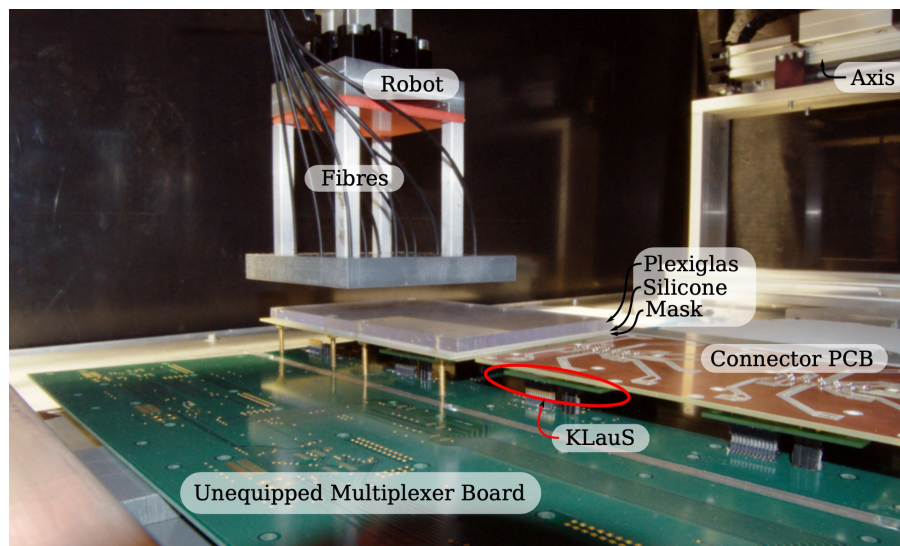


Previous Setups

Large-Tile-Tester, Heidelberg

Bachelor/Master Thesis

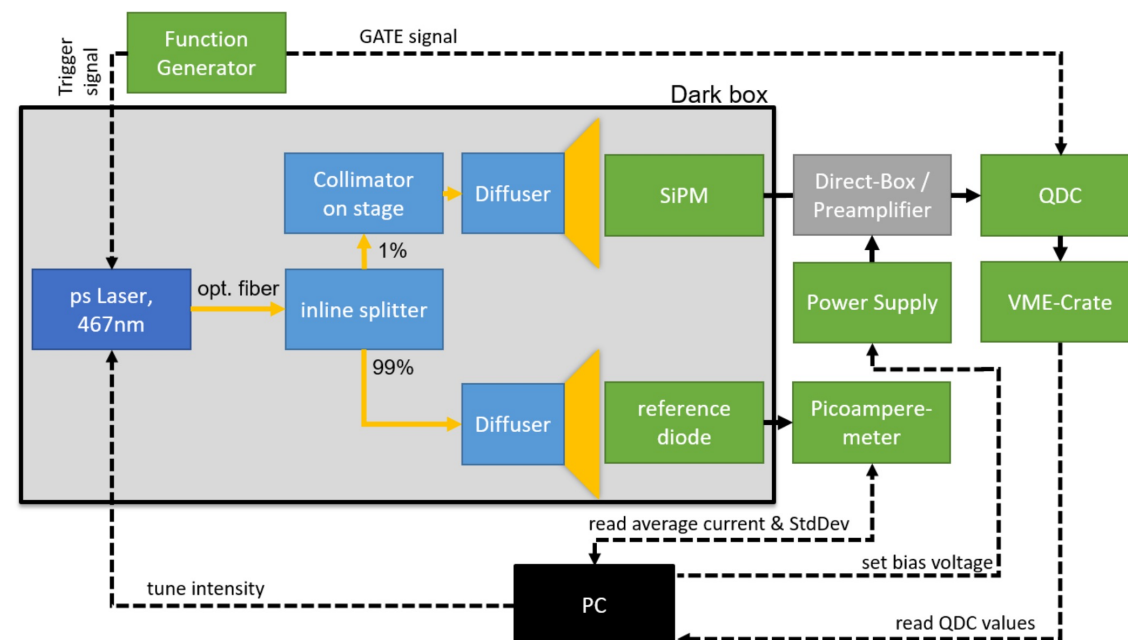
Felix Passenberg/Thorwald Klapdor-Kleingrothaus



- High quantity SiPM testing for ILD
- Automated measurements
- Fiber system on a robot head

Saturation Measurements, Mainz

Dissertation of Sascha Krause



- High intensity illumination
- Saturation region of SiPM with max 2668 Pixels
-> ≈ 40000 Pixels for our tests